Chipsmall

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We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!

Contact us

MC14585B

4-Bit Magnitude Comparator

The MC14585B 4–Bit Magnitude Comparator is constructed with complementary MOS (CMOS) enhancement mode devices. The circuit has eight comparing inputs (A3, B3, A2, B2, A1, B1, A0, B0), three cascading inputs (A < B, A = B, and A > B), and three outputs (A < B, A = B, and A > B). This device compares two 4–bit words (A and B) and determines whether they are "less than", "equal to", or "greater than" by a high level on the appropriate output. For words greater than 4–bits, units can be cascaded by connecting outputs (A > B), (A < B), and (A = B) to the corresponding inputs of the next significant comparator. Inputs (A < B), (A = B), and (A > B) on the least significant (first) comparator are connected to a low, a high, and a low, respectively.

Applications include logic in CPU's, correction and/or detection of instrumentation conditions, comparator in testers, converters, and controls.

Features

- Diode Protection on All Inputs
- Expandable
- Applicable to Binary or 8421−BCD Code
- Supply Voltage Range = 3.0 Vdc to 18 Vdc
- Capable of Driving Two Low−Power TTL Loads or One Low−Power Schottky TTL Load over the Rated Temperature Range
- Can be Cascaded − See Figure 3
- Pb−Free Packages are Available*

MAXIMUM RATINGS (Voltages Referenced to V_{SS})

Parameter	Symbol	Value	Unit
DC Supply Voltage Range	V_{DD}	−0.5 to +18.0	V
Input or Output Voltage Range (DC or Transient)	V_{in}, V_{out}	−0.5 to V_{DD} + 0.5	V
Input or Output Current (DC or Transient) per Pin	I_{in}, I_{out}	±10	mA
Power Dissipation per Package (Note 1)	P_D	500	mW
Ambient Temperature Range	T_A	−55 to +125	°C
Storage Temperature Range	T_{stg}	−65 to +150	°C
Lead Temperature (8−Second Soldering)	T_L	260	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.
1. Temperature Derating: Plastic "P and D/DW" Packages: – 7.0 mW/°C From 65°C To 125°C

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high−impedance circuit. For proper operation, V_{in} and V_{out} should be constrained to the range $V_{SS} \leq (V_{in}$ or $V_{out}) \leq V_{DD}$.

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either V_{SS} or V_{DD}). Unused outputs must be left open.
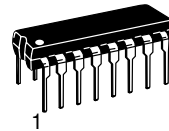
*For additional information on our Pb−Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.
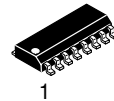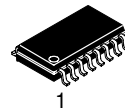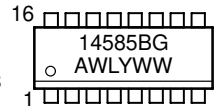
MARKING DIAGRAMS

PDIP−16
P SUFFIX
CASE 648

16
MC14585BCP
AWLYYWWG
1

SOIC−16
D SUFFIX
CASE 751B

16
14585BG
AWLYWW
1

SOEIAJ−16
F SUFFIX
CASE 966

16
MC14585B
ALYWG
1

A	= Assembly Location
WL, L	= Wafer Lot
YY, Y	= Year
WW, W	= Work Week
G	= Pb−Free Package

ORDERING INFORMATION

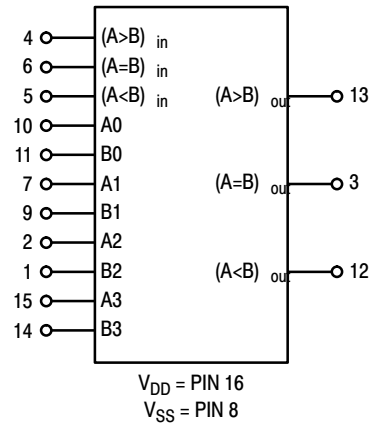| Device	Package	Shipping[†]
MC14585BCP	PDIP−16	25 Units / Rail
MC14585BCPG	PDIP−16 (Pb−Free)	25 Units / Rail
MC14585BD	SOIC−16	48 Units / Rail
MC14585BDG	SOIC−16 (Pb−Free)	48 Units / Rail
MC14585BDR2	SOIC−16	2500/Tape & Reel
MC14585BDR2G	SOIC−16 (Pb−Free)	2500/Tape & Reel
MC14585BFEL	SOEIAJ−16	2000/Tape & Reel
MC14585BFELG	SOEIAJ−16 (Pb−Free)	2000/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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PIN ASSIGNMENT

B2	1 ●	16	V_{DD}
A2	2	15	A3
$(A = B)_{out}$	3	14	B3
$(A > B)_{in}$	4	13	$(A > B)_{out}$
$(A < B)_{in}$	5	12	$(A < B)_{out}$
$(A = B)_{in}$	6	11	B0
A1	7	10	A0
V_{SS}	8	9	B1

BLOCK DIAGRAM

Pin	Signal
4	$(A>B)_{in}$
6	$(A=B)_{in}$
5	$(A<B)_{in}$
10	A0
11	B0
7	A1
9	B1
2	A2
1	B2
15	A3
14	B3

Outputs: $(A>B)_{out}$ → 13, $(A=B)_{out}$ → 3, $(A<B)_{out}$ → 12

V_{DD} = PIN 16
V_{SS} = PIN 8
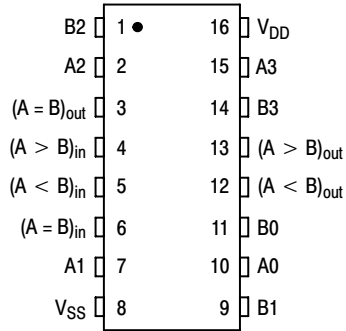
TRUTH TABLE (x = Don't Care)

Inputs							Outputs		
Comparing				Cascading					
A3, B3	A2, B2	A1, B1	A0, B0	A < B	A = B	A > B	A < B	A = B	A > B
A3 > B3	x	x	x	x	x	x	0	0	1
A3 = B3	A2 > B2	x	x	x	x	x	0	0	1
A3 = B3	A2 = B2	A1 > B1	x	x	x	x	0	0	1
A3 = B3	A2 = B2	A1 = B1	A0 > B0	x	x	x	0	0	1
A3 = B3	A2 = B2	A1 = B1	A0 = B0	0	0	x	0	0	1
A3 = B3	A2 = B2	A1 = B1	A0 = B0	0	1	x	0	1	0
A3 = B3	A2 = B2	A1 = B1	A0 = B0	1	0	x	1	0	0
A3 = B3	A2 = B2	A1 = B1	A0 = B0	1	1	x	1	1	0
A3 = B3	A2 = B2	A1 = B1	A0 < B0	x	x	x	1	0	0
A3 = B3	A2 = B2	A1 < B1	x	x	x	x	1	0	0
A3 = B3	A2 < B2	x	x	x	x	x	1	0	0
A3 < B3	x	x	x	x	x	x	1	0	0

MC14585B

ELECTRICAL CHARACTERISTICS (Voltages Referenced to V_{SS})

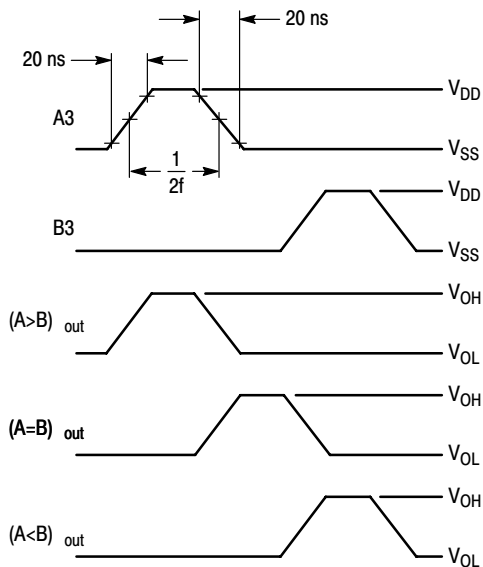| Characteristic	Symbol	V_{DD} Vdc	−55°C Min	−55°C Max	25°C Min	25°C Typ (Note 2)	25°C Max	125°C Min	125°C Max	Unit
Output Voltage "0" Level V_{in} = V_{DD} or 0	V_{OL}	5.0 10 15	– – –	0.05 0.05 0.05	– – –	0 0 0	0.05 0.05 0.05	– – –	0.05 0.05 0.05	Vdc
"1" Level V_{in} = 0 or V_{DD}	V_{OH}	5.0 10 15	4.95 9.95 14.95	– – –	4.95 9.95 14.95	5.0 10 15	– – –	4.95 9.95 14.95	– – –	Vdc
Input Voltage "0" Level (V_O = 4.5 or 0.5 Vdc) (V_O = 9.0 or 1.0 Vdc) (V_O = 13.5 or 1.5 Vdc)	V_{IL}	5.0 10 15	– – –	1.5 3.0 4.0	– – –	2.25 4.50 6.75	1.5 3.0 4.0	– – –	1.5 3.0 4.0	Vdc
"1" Level (V_O = 0.5 or 4.5 Vdc) (V_O = 1.0 or 9.0 Vdc) (V_O = 1.5 or 13.5 Vdc)	V_{IH}	5.0 10 15	3.5 7.0 11	– – –	3.5 7.0 11	2.75 5.50 8.25	– – –	3.5 7.0 11	– – –	Vdc
Output Drive Current (V_{OH} = 2.5 Vdc) Source (V_{OH} = 4.6 Vdc) (V_{OH} = 9.5 Vdc) (V_{OH} = 13.5 Vdc)	I_{OH}	5.0 5.0 10 15	− 3.0 − 0.64 − 1.6 − 4.2	– – – –	− 2.4 − 0.51 − 1.3 − 3.4	− 4.2 − 0.88 − 2.25 − 8.8	– – – –	− 1.7 − 0.36 − 0.9 − 2.4	– – – –	mAdc
(V_{OL} = 0.4 Vdc) Sink (V_{OL} = 0.5 Vdc) (V_{OL} = 1.5 Vdc)	I_{OL}	5.0 10 15	0.64 1.6 4.2	– – –	0.51 1.3 3.4	0.88 2.25 8.8	– – –	0.36 0.9 2.4	– – –	mAdc
Input Current	I_{in}	15	–	±0.1	–	±0.00001	±0.1	–	±1.0	μAdc
Input Capacitance (V_{in} = 0)	C_{in}	–	–	–	–	5.0	7.5	–	–	pF
Quiescent Current (Per Package)	I_{DD}	5.0 10 15	– – –	5.0 10 20	– – –	0.005 0.010 0.015	5.0 10 20	– – –	150 300 600	μAdc
Total Supply Current (Notes 3, 4) (Dynamic plus Quiescent, Per Package) (C_L = 50 pF on all outputs, all buffers switching)	I_T	5.0 10 15	\multicolumn{6}{c}{I_T = (0.6 μA/kHz) f + I_{DD} I_T = (1.2 μA/kHz) f + I_{DD} I_T = (1.8 μA/kHz) f + I_{DD}}						μAdc

2. Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.
3. The formulas given are for the typical characteristics only at 25°C.
4. To calculate total supply current at loads other than 50 pF: $I_T(C_L) = I_T$(50 pF) + $(C_L − 50)$ Vfk where: I_T is in μA (per package), C_L in pF, V = ($V_{DD} − V_{SS}$) in volts, f in kHz is input frequency, and k = 0.001.

SWITCHING CHARACTERISTICS (Note 5) (C_L = 50 pF, T_A = 25°C)

| Characteristic	Symbol	V_{DD}	Min	Typ (Note 6)	Max	Unit
Output Rise and Fall Time t_{TLH}, t_{THL} = (1.5 ns/pF) C_L + 25 ns t_{TLH}, t_{THL} = (0.75 ns/pF) C_L + 12.5 ns t_{TLH}, t_{THL} = (0.55 ns/pF) C_L + 9.5 ns	t_{TLH}, t_{THL}	5.0 10 15	– – –	100 50 40	200 100 80	ns
Turn−On, Turn−Off Delay Time t_{PLH}, t_{PHL} = (1.7 ns/pF) C_L + 345 ns t_{PLH}, t_{PHL} = (0.66 ns/pF) C_L + 147 ns t_{PLH}, t_{PHL} = (0.5 ns/pF) C_L + 105 ns	t_{PLH}, t_{PHL}	5.0 10 15	– – –	430 180 130	860 360 260	ns

5. The formulas given are for the typical characteristics only at 25°C.
6. Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.
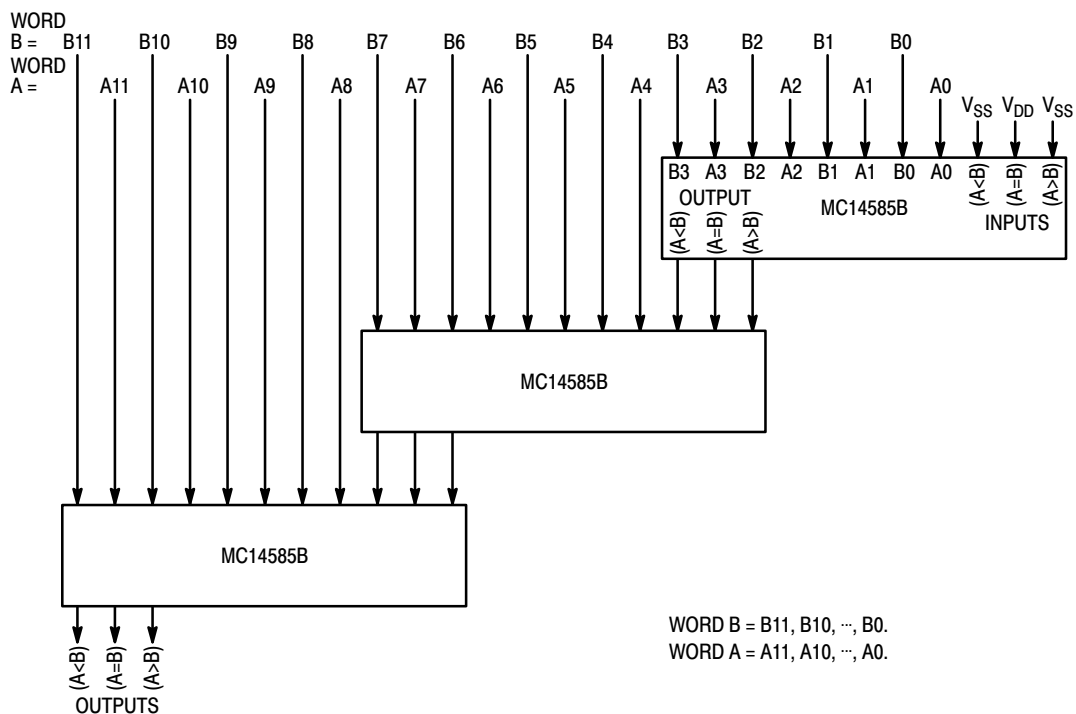
Inputs (A>B) and (A=B) high, and inputs B2, A2, B1,
A1, B0, A0 and (A<B) low.
f in respect to a system clock.

**Figure 1. Dynamic Power Dissipation
Signal Waveforms**
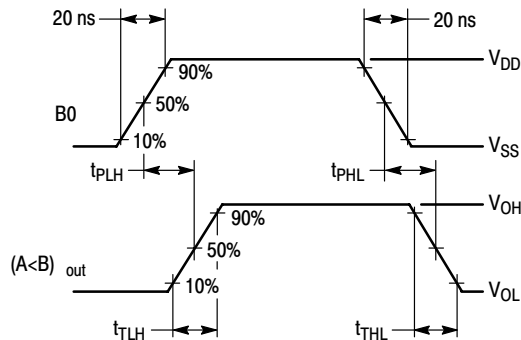
Inputs (A>B) and (A=B) high, and inputs B3, A3, B2,
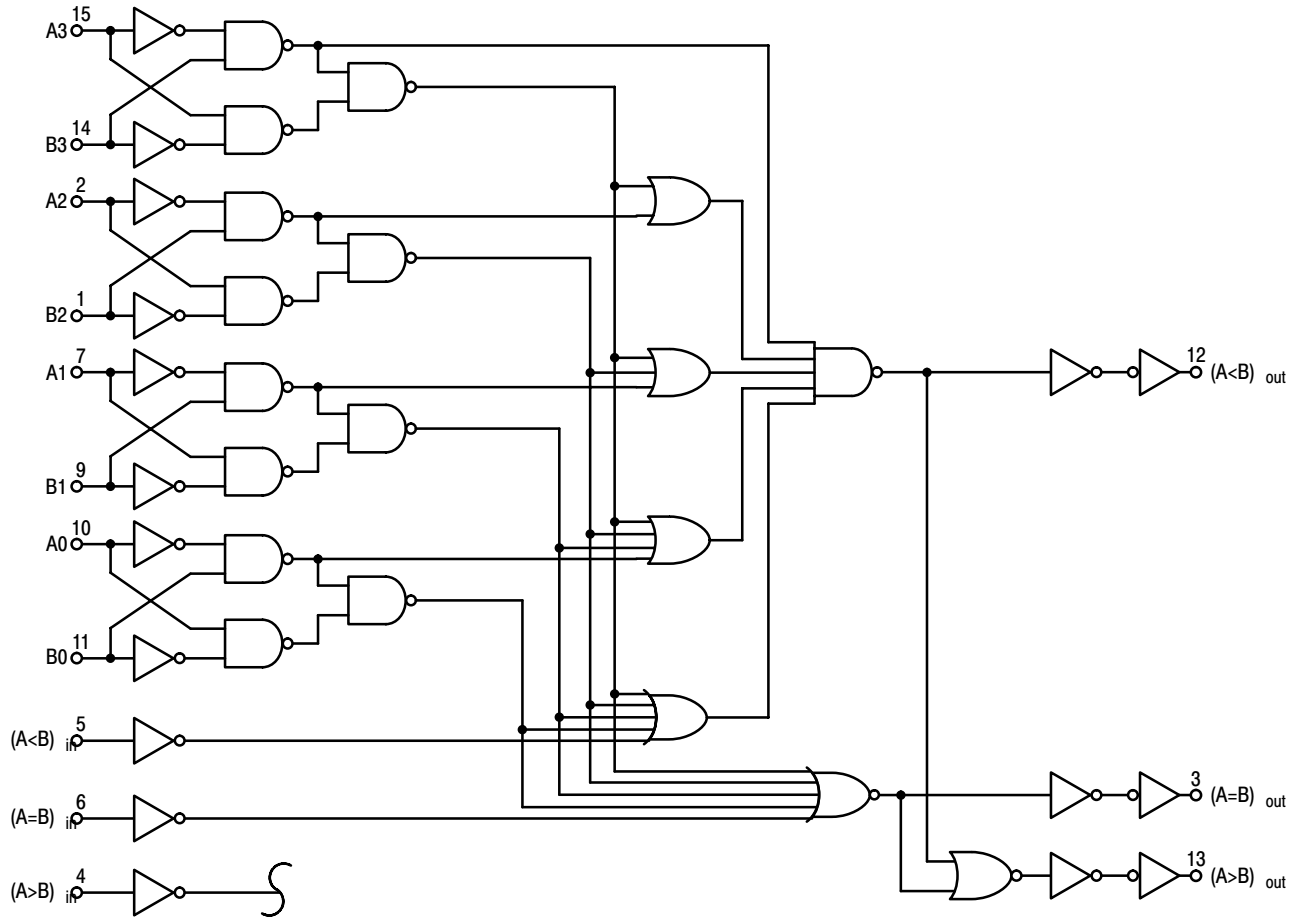A2, B1, A1, A0, and (A<B) low.

Figure 2. Dynamic Signal Waveforms

WORD B = B11, B10, ⋯, B0.
WORD A = A11, A10, ⋯, A0.

Figure 3. Cascading Comparators

# MC14585B

LOGIC DIAGRAM

MC14585B

PACKAGE DIMENSIONS

PDIP−16
CASE 648−08
ISSUE T
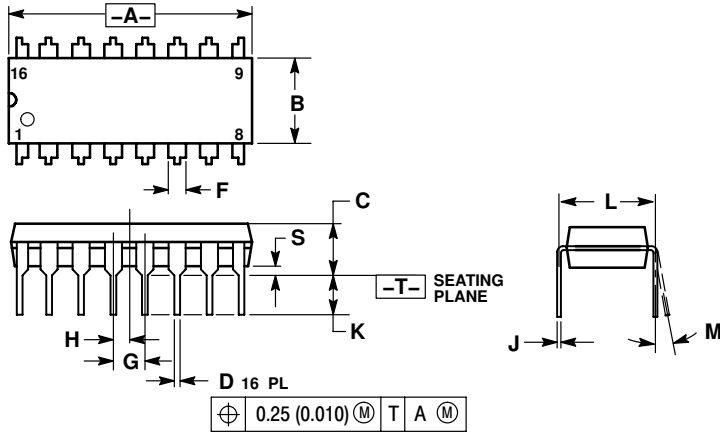
NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.
4. DIMENSION B DOES NOT INCLUDE MOLD FLASH.
5. ROUNDED CORNERS OPTIONAL.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.740	0.770	18.80	19.55
B	0.250	0.270	6.35	6.85
C	0.145	0.175	3.69	4.44
D	0.015	0.021	0.39	0.53
F	0.040	0.70	1.02	1.77
G	0.100 BSC		2.54 BSC	
H	0.050 BSC		1.27 BSC	
J	0.008	0.015	0.21	0.38
K	0.110	0.130	2.80	3.30
L	0.295	0.305	7.50	7.74
M	0 °	10 °	0 °	10 °
S	0.020	0.040	0.51	1.01

SOIC−16
CASE 751B−05
ISSUE J
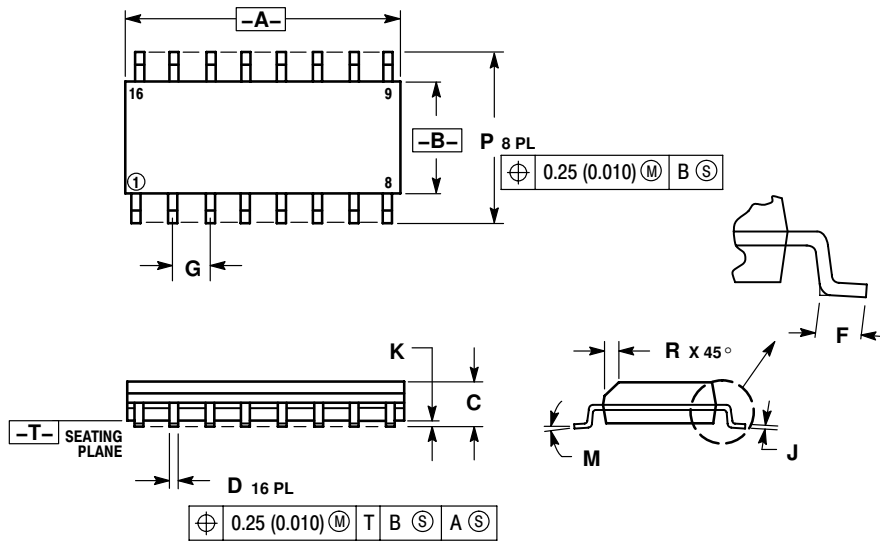
NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	9.80	10.00	0.386	0.393
B	3.80	4.00	0.150	0.157
C	1.35	1.75	0.054	0.068
D	0.35	0.49	0.014	0.019
F	0.40	1.25	0.016	0.049
G	1.27 BSC		0.050 BSC	
J	0.19	0.25	0.008	0.009
K	0.10	0.25	0.004	0.009
M	0 °	7 °	0 °	7 °
P	5.80	6.20	0.229	0.244
R	0.25	0.50	0.010	0.019

MC14585B

PACKAGE DIMENSIONS

SOEIAJ–16
CASE 966–01
ISSUE A
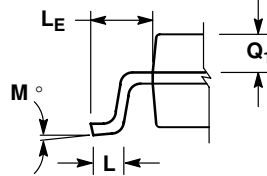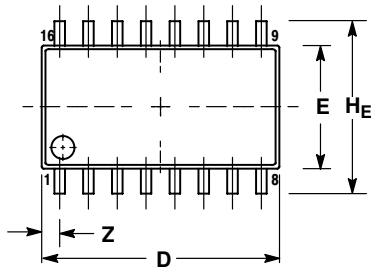
DETAIL P
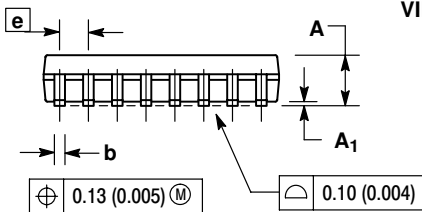
VIEW P

NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS AND ARE MEASURED AT THE PARTING LINE. MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
4. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
5. THE LEAD WIDTH DIMENSION (b) DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE LEAD WIDTH DIMENSION AT MAXIMUM MATERIAL CONDITION. DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OR THE FOOT. MINIMUM SPACE BETWEEN PROTRUSIONS AND ADJACENT LEAD TO BE 0.46 (0.018).

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	---	2.05	---	0.081
A₁	0.05	0.20	0.002	0.008
b	0.35	0.50	0.014	0.020
c	0.10	0.20	0.007	0.011
D	9.90	10.50	0.390	0.413
E	5.10	5.45	0.201	0.215
e	1.27 BSC		0.050 BSC	
H$_E$	7.40	8.20	0.291	0.323
L	0.50	0.85	0.020	0.033
L$_E$	1.10	1.50	0.043	0.059
M	0 °	10 °	0 °	10 °
Q₁	0.70	0.90	0.028	0.035
Z	---	0.78	---	0.031

MC14585B/D